NSN 5961-00-864-4057

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-864-4057 **Inclosure Material:** Glass **Overall Length:** 0.510 inches **Terminal Length:** 0.250 inches **Overall Height:** 0.200 inches **Overall Width:** 0.350 inches **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 1.4 forward voltage, dc all semiconductor device diode and 100.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: